



Spec No. :DS30-2001-351 Effective Date: 07/02/2019

Revision: C

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4



LED DISPLAY

LTS-3861JD

| <u>Rev</u> | <u>Description</u> | <u>By</u> | <u>Date</u> (DD/MM/YY) | | | |
|--|--------------------------------------|-----------|---------------------------|--|--|--|
| 01 | Preliminary Spec | Meg Huang | 07-05-2002 | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| Above data for PD and Customer tracking only | | | | | | |
| - | NPPR Received and Upload on system | Meg Huang | 07-05-2002 | | | |
| А | Add dimension and recommend PCB hole | Anon B. | 09-05-2019 | | | |
| | | | | | | |



1. Description

The LTS-3861JD is a 0.3-inch (7.62-mm) digit height single digit low current seven-segment display This device uses AllnGaP HYPER RED chips (AllnGaP epi on GaAs substrate). The display has a light gray Face and white segments.

1.1 Features

- 0.30 inch (7.62 mm) DIGIT HEIGHT
- CONTINUOUS UNIFORM SEGMENTS
- LOW POWER REQUIREMENT
- EXCELLENT CHARACTERS APPEARANCE
- HIGH BRIGHTNESS & HIGH CONTRAST
- WIDE VIEWING ANGLE
- SOLID STATE RELIABILITY
- CATEGORIZED FOR LUMINOUS INTENSITY
- LEAD-FREE PACKAGE (ACCORDING TO ROHS)

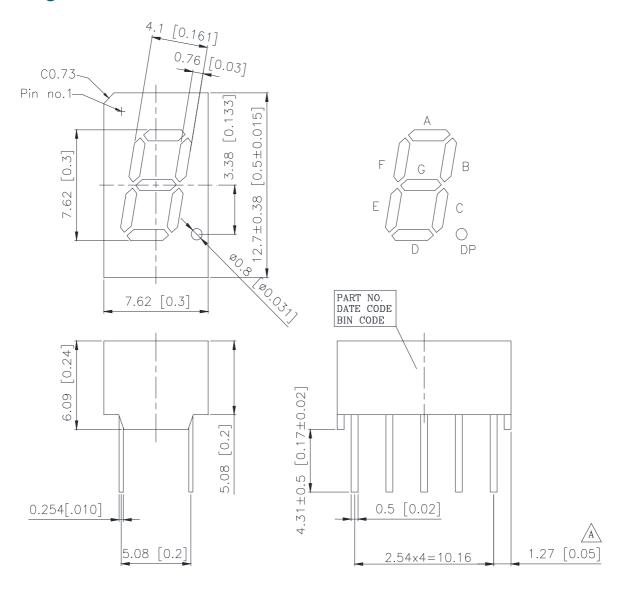
1.2 Device

| Part No | Description | | |
|-------------------|------------------|--|--|
| AllnGaP HYPER RED | Common anode | | |
| LTS-3861JD | Rt. Hand decimal | | |

Part No. : LTS-3861JD BNS-OD-FC002/A4



2. Package Dimensions

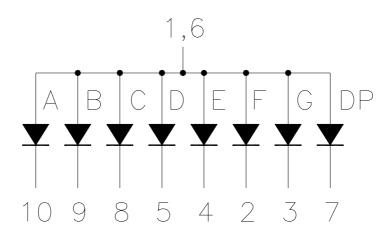


Notes:

- 1. All dimensions are in millimeters. Tolerances are \pm 0.25mm (0.01") unless otherwise noted.
- 2. Foreign materials on segment ≤10mils.
- Bubble in segment ≦10mils.
- 4. Bending≦1% of reflector length.
- Ink contamination (surface) ≦20mils.
- 6. Pin tip's shift tolerance is \pm 0.40 mm.
- 7. Recommend the best pcb hole: diameter 1.10 mm



3. Internal Circuit Diagram



4. Pin Connection

| No. | CONNECTION |
|-----|--------------|
| 1 | COMMON ANODE |
| 2 | CATHODE F |
| 3 | CATHODE G |
| 4 | CATHODE E |
| 5 | CATHODE D |
| 6 | COMMON ANODE |
| 7 | CATHODE DP |
| 8 | CATHODE C |
| 9 | CATHODE B |
| 10 | CATHODE A |



5. Rating and Characteristics

5.1. Absolute Maximum Rating at Ta=25℃

| Parameter | Maximum Rating | Unit | | |
|--|----------------|------|--|--|
| Power Dissipation Per Segment | 70 | mW | | |
| Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width) | 90 | mA | | |
| Continuous Forward Current Per Segment | 25 | mA | | |
| Derating Linear From 25℃ Per Segment | 0.28 | mA/℃ | | |
| Operating Temperature Range | -35℃ to +105℃ | | | |
| Storage Temperature Range | -35℃ to +105℃ | | | |

Solder Conditions: 1/16 inch below seating plane within 3 seconds at max 260℃ or temperature of unit (during assembly) not over max. temperature rating above.

5.2. Electrical / Optical Characteristics at Ta=25°C

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit | Test Condition |
|--|--------|------|------|------|------|----------------|
| Average Luminous Intensity | IV | 200 | 600 | | ucd | IF=1mA |
| Peak Emission Wavelength | λр | | 650 | | nm | IF=20mA |
| Spectral Line Half-Width | Δλ | | 20 | | nm | IF=20mA |
| Dominant Wavelength | λd | | 639 | | nm | IF=20mA |
| Forward Voltage Per Chip | VF | | 2.10 | 2.60 | V | IF=20mA |
| Reverse Current Per Segment (*2) | IR | | | 100 | μΑ | VR=5V |
| Luminous Intensity Matching Ratio (Similar Light Area) | IV-m | | | 2:1 | | IF=1mA |

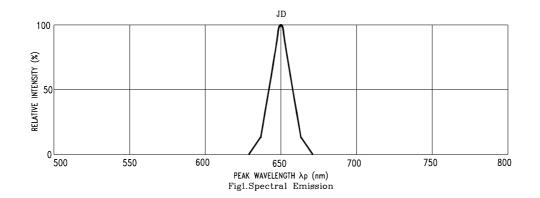
Notes:

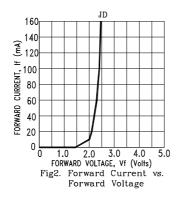
- 1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commission International De L'Eclariage) eye-response curve.
- 2. Reverse voltage is only for IR test. It cannot continue to operate at this situation.
- 3. Cross talk specification ≤ 2.5%.

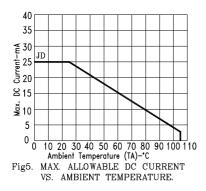


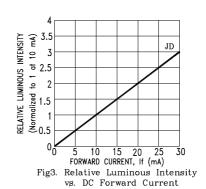
6. Typical Electrical / Optical Characteristics Curves

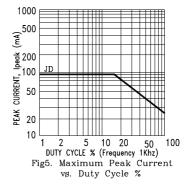
(25°C Ambient Temperature Unless Otherwise Noted)











NOTE : JD=AlInGaP HYPER RED